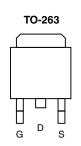


Vishay Siliconix

Automotive N-Channel 40 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	40				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0041				
I _D (A)	50				
Configuration	Single				

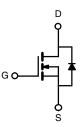


Top View

FEATURES

- TrenchFET® Power MOSFET
- Package with Low Thermal Resistance
- AEC-Q101 Qualified^d
- 100 % R_g and UIS Tested
- Material categorization:
 For definitions of compliance please see www.vishay.com/doc?99912





N-Channel MOSFET

ORDERING INFORMATION	
Package	TO-263
Lead (Pb)-free and Halogen-free	SQM50N04-4m1-GE3

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	LIMIT	UNIT			
Drain-Source Voltage	V_{DS}	40	V			
Gate-Source Voltage	V _{GS}	± 20	V			
Continuous Drain Currenta	T _C = 25 °C	1	50			
Continuous Drain Current	T _C = 125 °C	l _D	50			
Continuous Source Current (Diode Conduct	I _S	50	Α			
Pulsed Drain Current ^b	I _{DM}	200				
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	60			
Single Pulse Avalanche Energy	L = 0.1 min	E _{AS}	180	mJ		
Maximum Dawar Dissinationh	T _C = 25 °C	Б	150	W		
Maximum Power Dissipation ^b	T _C = 125 °C	P _D	50	VV		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to + 175	°C		

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	LIMIT	UNIT		
Junction-to-Ambient	PCB Mount ^c	R_{thJA}	40	°C/W		
Junction-to-Case (Drain)		R _{thJC}	1	C/VV		

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR-4 material).
- d. Parametric verification ongoing.



Vishay Siliconix

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static						L	ı	
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		40	-	-	V	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$		3.0	3.5	V	
Gate-Source Leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	± 100	nA	
		V _{GS} = 0 V	V _{DS} = 40 V	-	-	1		
Zero Gate Voltage Drain Current	I_{DSS}	$V_{GS} = 0 V$	$V_{DS} = 40 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$	-	-	50	μΑ	
		V _{GS} = 0 V	V _{DS} = 40 V, T _J = 175 °C	-	-	250	1	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	50	-	-	Α	
		V _{GS} = 10 V	I _D = 30 A	-	0.0030	0.0041		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 30 A, T _J = 125 °C	-	-	0.0068	Ω	
		V _{GS} = 10 V	I _D = 30 A, T _J = 175 °C	-	-	0.0082	1	
Forward Transconductance ^b	9fs	V _{DS} = 15 V, I _D = 30 A		-	200	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}			-	5372	6715		
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V V _{DS} = 25 V, f = 1 MHz		512	640	рF	
Reverse Transfer Capacitance	C _{rss}			-	256	320		
Total Gate Charge ^c	Qg			-	70	105		
Gate-Source Charge ^c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 20 \text{ V}, I_D = 50 \text{ A}$	-	16	-	nC	
Gate-Drain Charge ^c	Q _{gd}			-	12.6	-		
Gate Resistance	R_g		f = 1 MHz		1.86	2.8	Ω	
Turn-On Delay Time ^c	t _{d(on)}	$V_{DD} = 20 \text{ V, } R_L = 0.4 \Omega$ $I_D \cong 50 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 1 \Omega$		-	12	18		
Rise Time ^c	t _r			-	5	8	ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	35	53		
Fall Time ^c	t _f			-	9	14		
Causes Duain Diada Datings and Chau	acteristics ^b	•						
Source-Drain Diode Ratings and Chara								
Pulsed Current ^a	I _{SM}			-	-	200	Α	

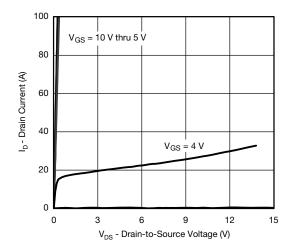
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

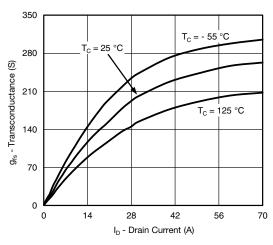
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



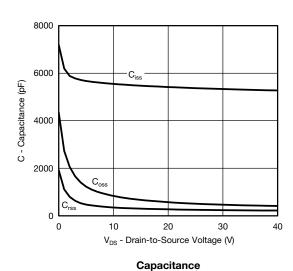
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Output Characteristics



Transconductance

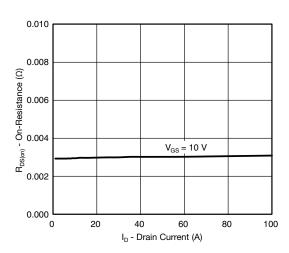


100

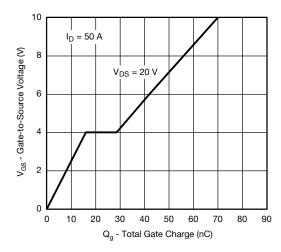
80

(Y) transport of the property of the

Transfer Characteristics

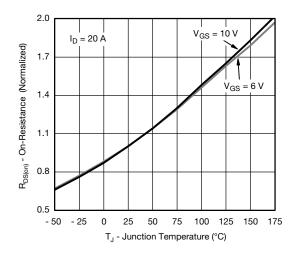


On-Resistance vs. Drain Current

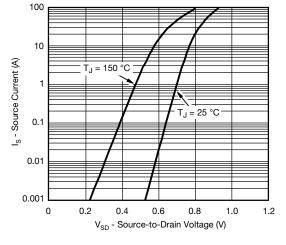




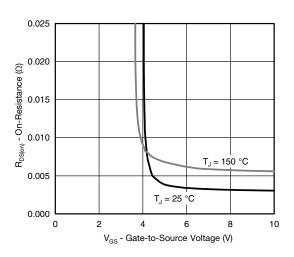
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



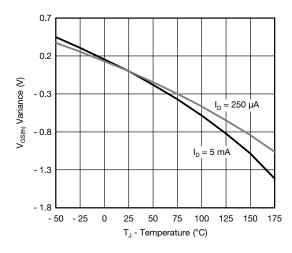
On-Resistance vs. Junction Temperature



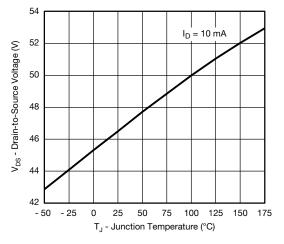
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



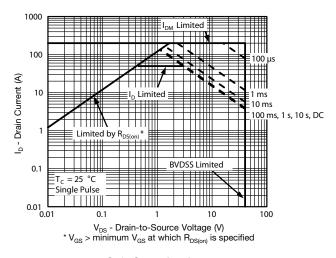
Threshold Voltage



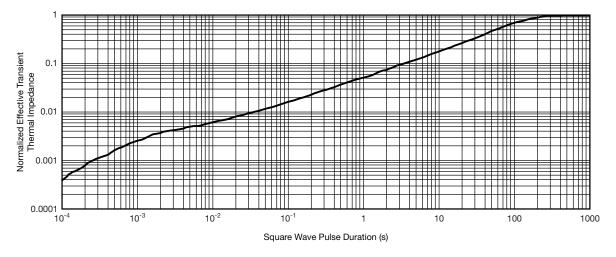
Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



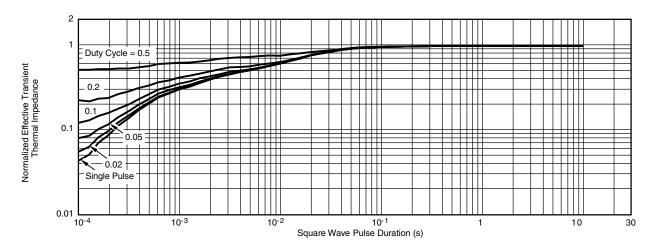
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

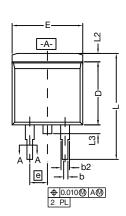
Note

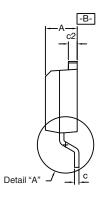
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

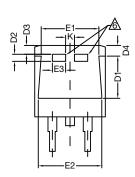
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TO-263 (D²PAK): 3-LEAD

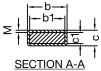








DETAIL A (ROTATED 90°)



_ - b1 	
≥ 	- -

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

6. This feature is for thick lead.

		INCHES		INCHES MILLIMETE			METERS
DIM.		MIN.	MAX.	MIN.	MAX.		
Α		0.160	0.190	4.064	4.826		
	b	0.020	0.039	0.508	0.990		
	b1	0.020	0.035	0.508	0.889		
	b2	0.045	0.055	1.143	1.397		
c*	Thin lead	0.013	0.018	0.330	0.457		
C	Thick lead	0.023	0.028	0.584	0.711		
c1	Thin lead	0.013	0.017	0.330	0.431		
CI	Thick lead	0.023	0.027	0.584	0.685		
	c2	0.045	0.055	1.143	1.397		
	D	0.340	0.380	8.636	9.652		
D1		0.220	0.240	5.588	6.096		
D2		0.038	0.042	0.965	1.067		
D3		0.045	0.055	1.143	1.397		
D4		0.044	0.052	1.118	1.321		
E		0.380	0.410	9.652	10.414		
	E1	0.245	-	6.223 -			
	E2	0.355	0.375	9.017	9.525		
	E3	0.072	0.078	1.829	1.981		
е		0.100) BSC	2.54 BSC			
K		0.045	0.055	1.143	1.397		
	L	0.575	0.625	14.605	15.875		
	L1	0.090	0.110	2.286	2.794		
	L2	0.040	0.055	1.016	1.397		
L3		0.050	0.070	1.270	1.778		
	L4	0.010) BSC	0.254 BSC			
	М	-	0.002	-	0.050		
ECN: T13-0707-Rev. K, 30-Sep-13							

DWG: 5843





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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